

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Hire application of:

John G. DeSteese and Larry C. Olsen

Application No. 10/727,062

Filed: December 2, 2003 Confirmation No. 4870

THERMOELECTRIC POWER SOURCE For:

UTILIZING AMBIENT ENERGY

HARVESTING FOR REMOTE SENSING

AND TRANSMITTING

Examiner: Alan D. Diamond

Art Unit: 1753

Attorney Reference No. 23-69853-01

CERTIFICATE OF MAILING

I hereby certify that this paper and the documents referred to as being attached or enclosed herewith are being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: COMMISSIONER FOR PATENTS, P.O. BOX 1450, ALEXANDRIA, VA 22313-1450 on the date shown below.

Attorney or Agent for Applicant(s) Date Mailed

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COMMISSIONER FOR PATENTS P.O. BOX 1450 ALEXANDRIA, VA 22313-1450

Listed on the accompanying form PTO-1449 and enclosed herewith are several Englishlanguage documents. Applicants respectfully request that these documents be listed as references cited on the issued patent.

Copies of United States patents and United States published patent applications do not have to be provided to the Patent Office (37 C.F.R. 1.98(a)(2)(ii)). Copies of unpublished U.S. applications do not have to be provided, as long as the application is available on PAIR, as this requirement of 37 C.F.R. § 1.98(a)(2)(iii) has been waived by the United States Patent and Trademark Office pursuant to the Official Gazette Notice on October 19, 2004 (1287 OG 163). Applicants will provide copies of such patents or applications upon request. Copies of the cited non-patent, non-application documents are enclosed.

Applicants filed this Information Disclosure Statement ("IDS") before the mailing date of a first Office action on the merits. As a result, no fee should be required to file this IDS. However, if the Patent Office determines that a fee is required for Applicants to file this IDS,

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The filing of this IDS shall not be construed to be an admission that the information cited in the statement is, or is considered to be, prior art or otherwise material to patentability as defined in 37 C.F.R. §1.56.

Respectfully submitted,

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ATION DISCLOSURE STATEMENT **BY APPLICANT** MAY 3 1 2005

Attorney Docket Number	23-69853-01
Application Number	10/727,062
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First Named Inventor	John G. DeSteese
Art Unit	3744
Examiner Name	Not yet assigned

U.S. PATENT DOCUMENTS

& THADE Copies of U.S. Patent documents do not need to be provided, unless requested by the Patent and Trademark Office. For patents, provide the patent number and the issue date. For published U.S. applications, provide the publication number and the publication date. For unpublished pending natent applications, provide the application number and the filing date.

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EXAMINER	DATE
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^{*} Examiner: Initial if reference considered, whether or not in conformance with MPEP 609. Draw line through cite if not in conformance and not considered. Include copy of this form with next communication to applicant.

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11/21/02).

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